# Quad 2-input NAND Schmitt trigger BU4093B / BU4093BF / BU4093BFV

The BU4093B, BU4093BF, and BU4093BFV are 4-circuit, 2-input NAND gates whose input pins all have a Schmitt trigger function.

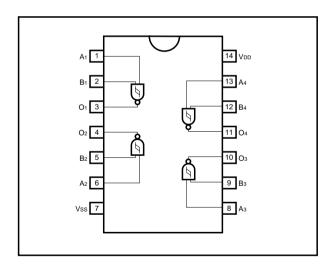
As the circuit threshold voltages are different when the input waveform rises and when it falls (V<sub>IH</sub>, V<sub>IL</sub>), they can be used for line receivers, waveform rectification, multivibrators, and other purposes in addition to the customary usage as a NAND gate. They may be used in place of the BU4011B which uses the same pin connection.

#### Features

- 1) Low power dissipation.
- 2) Wide range of operating power supply voltages.
- 3) High input impedance.

- 4) High fan-out.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

## Block diagram



#### Truth table

INF	OUTPUT	
Α	В	001701
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

# ●Absolute maximum ratings (Vss = 0V, Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	V <sub>DD</sub>	<b>−</b> 0.3 ~ <b>+</b> 18	V
Power dissipation	Pd	1000 (DIP), 450 (SOP), 350 (SSOP)	mW
Operating temperature	Topr	<b>− 40 ~ + 85</b>	°C
Storage temperature	Tstg	− 55 ~ <b>+</b> 150	°C
Input voltage	Vin	- 0.3 ~ V <sub>DD</sub> + 0.3	V

#### Electrical characteristics

DC characteristics (unless otherwise noted, Vss = 0V, Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	V <sub>DD</sub> (V)	Conditions	Measurement circuit
Input high level voltage	Vıн	3.5	_	_	V	5	_	Fig.1
		7.0	_	_		10		
		11.0	_	_		15		
		_	_	1.5	V	5	_	Fig.1
Input low level voltage	VIL	_	_	3.0		10		
		_	_	4.0		15		
Input high level current	Іін	_	_	0.3	μΑ	15	VIH = 15V	Fig.1
Input low level current	lı∟	_	_	- 0.3	μΑ	15	VIL = 0V	Fig.1
		4.95	_	_		5	Io = 0mA	
Output high level voltage	Vон	9.95	_	_	V	10		Fig.1
		14.95	_	_		15		
Output low level voltage	Vol	_	_	0.05	V	5	Io = 0mA	Fig.1
		_	_	0.05		10		
		_	_	0.05		15		
	Іон	- 0.44	_	_	mA	5	Vон = 4.6V	Fig.1
Output high level current		- 1.1	_	_		10	Vон = 9.5V	
		- 3.0	_	_		15	Vон = 13.5V	
Output low level current	loL	0.44	_	_	mA	5	Vol = 0.4V	Fig.1
		1.1	_	_		10	Vol = 0.5V	
		3.0	_	_		15	Vol = 1.5V	
Static current dissipation	lod	_	_	1	μА	5	VI = VDD or GND	Fig.1
		_	_	2		10		
		_	_	4		15		
Hysteresis voltage	Vн	0.17	_	0.39		5	_	Fig.3
		0.25	_	0.60	V	10		
		0.33	_	0.90		15		

Switching characteristics (unless otherwise noted, Vss = 0V, Ta = 25°C, CL = 50pF)

Parameter	Symbol	Min.	Тур.	Max.	Unit.	V <sub>DD</sub> (V)	Conditions	Measurement circuit
Output rise time	tтьн	_	100	_	ns	5	_	Fig.2
		_	50	_		10		
		_	40	_		15		
Output fall time	tтн∟	_	100	_	ns	5	_	Fig.2
		_	50	_		10		
		_	40	_		15		
Propagation delay time, "L" to "H"	tрLH	_	125	_	ns	5	_	Fig.2
		_	50	_		10		
		_	40	_		15		
Propagation delay time, "H" to "L"	tрнL	_	125	_	ns	5	_	Fig.2
		_	50	_		10		
		_	40	_		15		
Input capacitance	Cin	_	5	_	pF	_	_	_

#### Measurement circuits

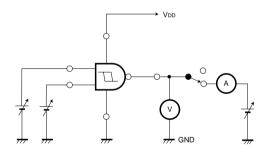


Fig. 1 DC characteristics

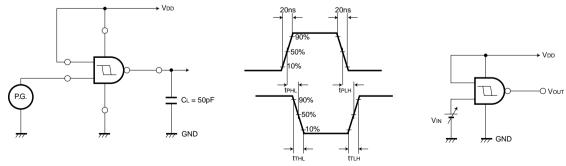


Fig. 2 Switching characteristic

Fig. 3 Hysteresis voltage

#### Electrical characteristic curve

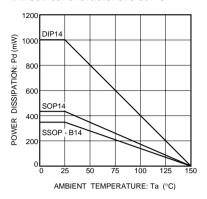
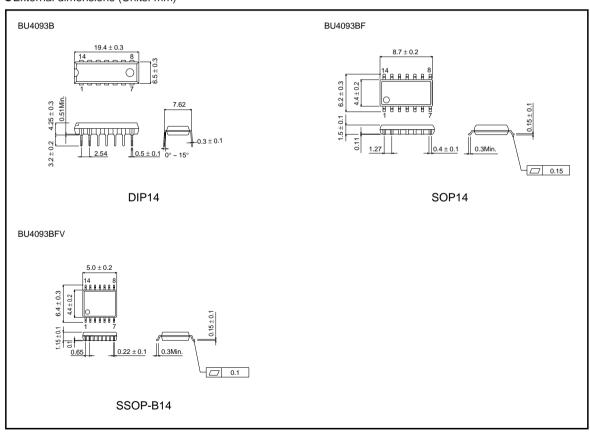


Fig. 4 Power dissipation vs. Ta

### External dimensions (Units: mm)



#### **Notes**

- No technical content pages of this document may be reproduced in any form or transmitted by any
  means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
  product described in this document are for reference only. Upon actual use, therefore, please request
  that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
  use and operation. Please pay careful attention to the peripheral conditions when designing circuits
  and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document use silicon as a basic material.
   Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

